NSN 5961-00-838-1141

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Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

Internal Junction Configuration:

Npn

Mounting Method:

mour

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

45.0 breakdown voltage, collector-to-base, emitter open and 45.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

25.00 milliamperes source cutoff current

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release2595 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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